Hex Inverter Buffers / Drivers with Open Drain Outputs

# HITACHI

ADE-205-296A (Z) 2nd Edition February 2000

#### **Description**

The HD74LV06A has six inverter buffers / drivers with open drain outputs in a 14-pin package. Low-voltage and high-speed operation is suitable for the battery-powered products (e.g., notebook computers), and the low-power consumption extends the battery life.

#### **Features**

- $V_{CC} = 2.0 \text{ V to } 5.5 \text{ V operation}$
- All inputs  $V_{IH}$  (Max.) = 5.5 V (@ $V_{CC}$  = 0 V to 5.5 V)
- All outputs  $V_0$  (Max.) = 5.5 V (@ $V_{CC}$  = 0 V)
- Typical  $V_{OL}$  ground bounce < 0.8 V (@ $V_{CC}$  = 3.3 V, Ta = 25°C)
- Typical  $V_{OH}$  undershoot > 2.3 V (@ $V_{CC}$  = 3.3 V, Ta = 25°C)
- Output current  $\pm 8 \text{ mA}$  (@V<sub>CC</sub> = 3.0 V to 3.6 V),  $\pm 16 \text{ mA}$  (@V<sub>CC</sub> = 4.5 V to 5.5 V)

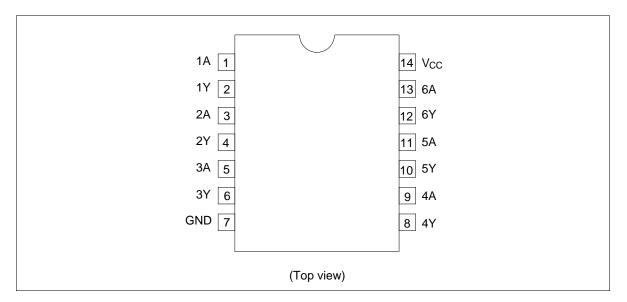
#### **Function Table**

Input A	Output Y
L	Н
Н	L

Note: H: High level L: Low level



# **Pin Arrangement**



### **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Conditions
Supply voltage range	V <sub>cc</sub>	-0.5 to 7.0	V	
Input voltage range*1	Vı	-0.5 to 7.0	V	
Output voltage range*1,2	Vo	$-0.5$ to $V_{cc}$ + 0.5	V	Output: H or L
		-0.5 to 7.0	-	V <sub>cc</sub> : OFF
Input clamp current	I <sub>IK</sub>	-20	mA	V <sub>1</sub> < 0
Output clamp current	I <sub>OK</sub>	<b>-</b> 50	mA	V <sub>o</sub> < 0
Continuous output current	Io	35	mA	$V_{o} = 0$ to $V_{cc}$
Continuous current through $V_{cc}$ or GND	I <sub>CC</sub> or I <sub>GND</sub>	±50	mA	
Maximum power dissipation at Ta = 25°C (in still air)*3	P <sub>T</sub>	785	mW	SOP
		500	-	TSSOP
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

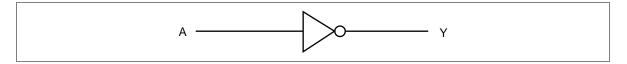
- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

# **Recommended Operating Conditions**

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V <sub>cc</sub>	2.0	5.5	V	
Input voltage range	V <sub>I</sub>	0	5.5	V	
Output voltage range	Vo	0	5.5	V	
Output current	I <sub>OL</sub>	_	50	μΑ	V <sub>CC</sub> = 2.0 V
		_	2	mA	$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
		_	8		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		_	16		$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
Input transition rise or fall rate	Δt/Δν	0	200	ns/V	$V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$
		0	100		$V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$
		0	20	<del></del>	$V_{CC} = 4.5 \text{ to } 5.5 \text{ V}$
Operating free-air temperature	Та	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

# Logic Diagram



### **DC Electrical Characteristics**

#### • $Ta = -40 \text{ to } 85^{\circ}C$

Item	Symbol	V <sub>cc</sub> (V)*	Min	Тур	Max	Unit	Test Conditions
Input voltage	V <sub>IH</sub>	2.0	1.5	_	_	V	
		2.3 to 2.7	$V_{cc} \times 0.7$	_	_	=	
		3.0 to 3.6	$V_{cc} \times 0.7$	_	_	-	
		4.5 to 5.5	$V_{\rm cc} \times 0.7$	_	_	='	
	V <sub>IL</sub>	2.0	_	_	0.5	='	
		2.3 to 2.7	_	_	$V_{\text{CC}} \times 0.3$	='	
		3.0 to 3.6	_	_	$V_{cc} \times 0.3$	=	
		4.5 to 5.5	_	_	$V_{cc} \times 0.3$	='	
Output voltage	V <sub>OL</sub>	Min to Max	_	_	0.1	V	I <sub>OL</sub> = 50 μA
		2.3	_	_	0.4	-	I <sub>OL</sub> = 2 mA
		3.0	_	_	0.44	-	I <sub>OL</sub> = 8 mA
		4.5	_	_	0.55	=	I <sub>OL</sub> = 16 mA
Input current	I <sub>IN</sub>	0 to 5.5	_	_	±1	μΑ	V <sub>IN</sub> = 5.5 V or GND
Quiescent supply current	I <sub>cc</sub>	5.5	_	_	20	μΑ	$V_{IN} = V_{CC}$ or GND, $I_0 = 0$
Output leakage current	I <sub>OFF</sub>	0	_	_	5	μΑ	V <sub>o</sub> = 5.5 V
Input capacitance	C <sub>IN</sub>	3.3	_	2.3	_	pF	$V_{I} = V_{CC}$ or GND

Note: For conditions shown as Min or Max use the appropriate values under recommended operating conditions.

# **Switching Characteristics**

# • $V_{CC} = 2.5 \pm 0.2 \text{ V}$

		Ta = 2	25°C		Ta = -4	40 to 85°C				
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Test Conditions	FROM (Input)	TO (Output)
Propagation	t <sub>PLH</sub>	_	4.7	10.4	1.0	13.0	ns	C <sub>L</sub> = 15 pF	Α	Υ
delay time		_	9.5	15.2	1.0	18.0	_	C <sub>L</sub> = 50 pF	-	
	t <sub>PHL</sub>	_	5.4	10.4	1.0	13.0	-	C <sub>L</sub> = 15 pF	-	
		_	7.9	15.2	1.0	18.0		C <sub>L</sub> = 50 pF		

### • $V_{CC} = 3.3 \pm 0.3 \text{ V}$

		Ta = 2	25°C		Ta = -4	10 to 85°C				
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Test Conditions	FROM (Input)	TO (Output)
Propagation	t <sub>PLH</sub>	_	4.0	7.1	1.0	8.5	ns	C <sub>L</sub> = 15 pF	А	Υ
delay time		_	7.3	10.6	1.0	12.0		C <sub>L</sub> = 50 pF	-	
	t <sub>PHL</sub>	_	4.3	7.1	1.0	8.5	-	C <sub>L</sub> = 15 pF	-	
		_	5.8	10.6	1.0	12.0	-	C <sub>L</sub> = 50 pF	-	

# • $V_{CC} = 5.0 \pm 0.5 V$

		Ta = 2	25°C		Ta = -4	10 to 85°C				
Item	Symbol	Min	Тур	Max	Min	Max	Unit	Test Conditions	FROM (Input)	TO (Output)
Propagation	t <sub>PLH</sub>	_	3.3	5.5	1.0	6.5	ns	C <sub>L</sub> = 15 pF	A	Υ
delay time		_	5.6	7.5	1.0	8.5	-	C <sub>L</sub> = 50 pF	-	
	t <sub>PHL</sub>	_	3.4	5.5	1.0	6.5	-	C <sub>L</sub> = 15 pF	-	
		_	4.1	7.5	1.0	8.5	=	C <sub>L</sub> = 50 pF	=	

# **Operating Characteristics**

•  $C_L = 50 pF$ 

25°C
25°C

Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Unit	Test Conditions
Power dissipation capacitance	$C_{\mathtt{PD}}$	3.3	_	9.6	_	pF	f = 10 MHz
		5.0	_	11.4	_		

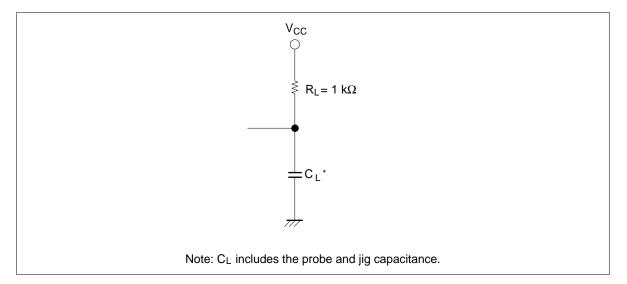
### **Noise Characteristics**

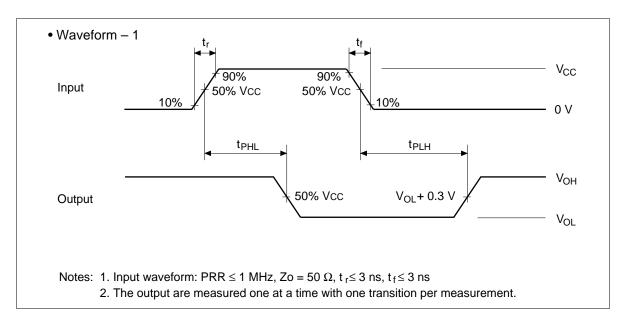
•  $C_L = 50 pF$ 

Ta	=	25°	С

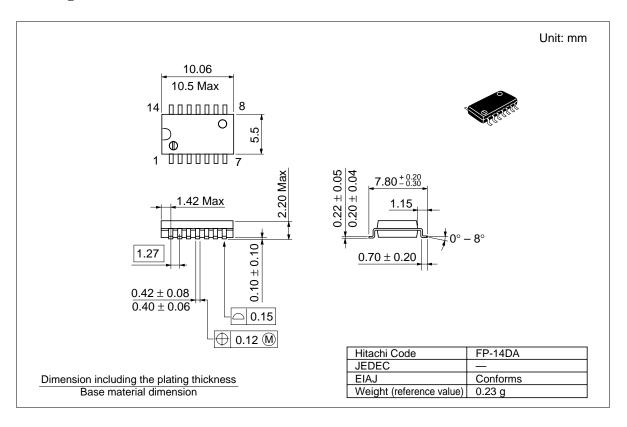
Item	Symbol	V <sub>cc</sub> (V)	Min	Тур	Max	Unit	<b>Test Conditions</b>
Quiet output, maximum dynamic V <sub>OL</sub>	$V_{OL(P)}$	3.3	_	0.3	0.8	V	
Quiet output, minimum dynamic V <sub>OL</sub>	$V_{OL(V)}$	3.3	_	-0.1	-0.8		
High-level dynamic input voltage	$V_{\text{IH (D)}}$	3.3	2.31	_	_	V	
Low-level dynamic input voltage	$V_{IL(D)}$	3.3	_	_	0.99		

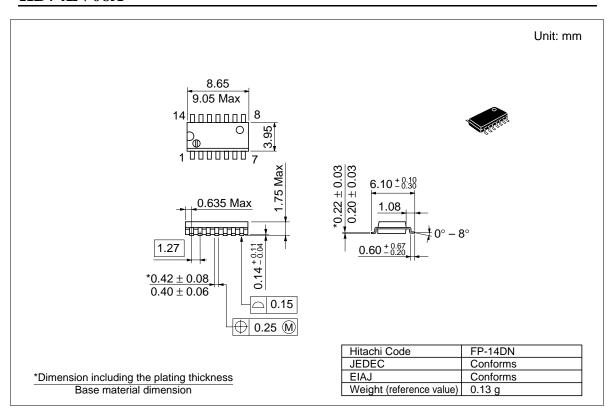
#### **Test Circuit**

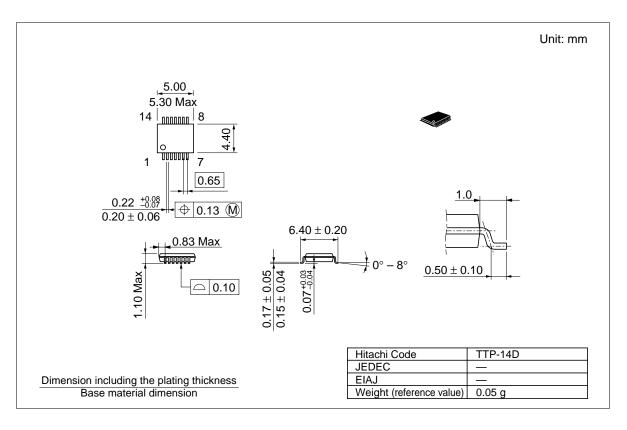




# **Package Dimensions**







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